3.0 A, Low Dropout Linear **Regulator with Enable**

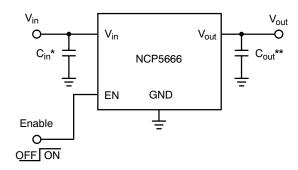
The NCP5666 is a high performance, low dropout linear regulator designed for high power applications that require up to 3.0 A current with Enable. A thermally robust, 5 pin D²PAK, combined with an architecture that offers low ground current (independent of load), provides for a superior high-current LDO solution.

Features

- ±1% Output Voltage Accuracy
- Ultra-Fast Transient Response (Settling Time: 1-3 µs)
- Low Noise Without Bypass Capacitor (57 μV_{rms})
- Low Ground Current Independent of Load (3.0 mA Maximum)
- Enable Function
- Current Limit Protection
- Thermal Protection
- Power Supply Rejection Ratio > 65 dB
- Stable with Aluminum, Tantalum and Ceramic Capacitors
- Pin Compatible with Semtech Device
- This is a Pb-Free Device

Applications

- Servers
- ASIC Power Supplies
- Post Regulation for Power Supplies
- Constant Current Source
- Networking Equipment
- Gaming and STB Modules



* C_{in} - 4.7 μF to 220 μF recommended **Cout - 2.2 μ F to 220 μ F recommended

See more details in the Application Information section

Figure 1. Typical Application Circuit



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D²PAK CASE 936A



MARKING

xx = Voltage Option 25 = 2.5 V

50 = 5.0 V

= Assembly Location

WL = Wafer Lot = Year WW = Work Week = Pb-Free

Tab = GND Pin 1. V_{in}

2. EN

3. GND

4. NC

5. Vout

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 8 of this data sheet.

PIN FUNCTION DESCRIPTION

Pin No.	Pin Name	Description
1	V _{in}	Positive Power Supply Input Voltage
2	EN	Enable. This pin allows for on/off control of the regulator. To disable the device, connect to GND. If this function is not in use, connect to $V_{\rm in}$.
3, Tab	GND	Power Supply Ground
4	NC	Not Connected. PCB runs allowable.
5	V _{out}	Regulated Output Voltage

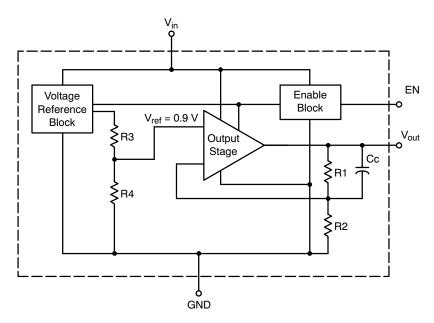


Figure 2. Block Diagram

ABSOLUTE MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Input Voltage (Note 1)	V _{in}	18	Vdc
Output Pin Voltage	V _{out}	-0.3 to (V _{in} + 0.3)	V
Enable Pin Voltage	V _{EN}	-0.3 to (V _{in} + 0.3)	V
Maximum Junction Temperature	T _{J(max)}	150	°C
Storage Temperature Range	T _{stg}	-55 to +150	°C
Moisture Sensitivity Level	MSL	1	-
ESD Capability, Human Body Model (Note 2)	ESD _{HBM}	2000	V
ESD Capability, Machine Model (Note 2)	ESD _{MM}	200	V

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

THERMAL CHARACTERISTICS

Rating	Symbol	Value	Unit
Thermal Characteristics (Note 1) Thermal Resistance Junction-to-Ambient (Note 3) Thermal Resistance Junction-to-Case	R _{θJA} R _{θJC}	45 5.0	°C/W

OPERATING RANGES

Rating	Symbol	Value	Unit
Operating Input Voltage (Note 1)	V _{in}	(V _{out} + V _{DO}) to 9	V
Operating Ambient Temperature Range	T _A	-40 to +85	°C

^{1.} Refer to Electrical Characteristics and Application Information for Safe Operating Area.

Machine Model (MM) JESD 22-A115-A.

This device series contains ESD protection and exceeds the following tests:
 Human Body Model (HBM) JESD 22-A114-B

^{3.} As measured using a copper heat spreading area of 650 mm², 1 oz copper thickness.

ELECTRICAL CHARACTERISTICS ($V_{in} = V_{out(nom)} + 1.5 \text{ V}$, $V_{EN} = V_{in}$, for typical values $T_A = 25^{\circ}\text{C}$, for min/max values $T_A = -40^{\circ}\text{C}$ to 85°C, C_{in} = 100 μ F, C_{out} = 33 μ F, unless otherwise noted. (Note 4))

Characteristic	Symbol	Min	Тур	Max	Unit
Output Voltage (Note 6) 2.5 V Regulator	V _{out}				V
$T_A = 25$ °C ($V_{in} = 4.0 \text{ V to } 7.0 \text{ V}, I_{out} = 10 \text{ mA to } 3.0 \text{ A}$)		2.475 (-1%)	2.500	2.525 (+1%)	
$T_A = -20 \text{ to } +125^{\circ}\text{C} \text{ (V}_{in} = 4.0 \text{ V to } 7.0 \text{ V, I}_{out} = 10 \text{ mA to } 3.0 \text{ A)}$		2.462 (-1.5%)	2.500	2.538 (+1.5%)	
$T_A = -40 \text{ to } +150^{\circ}\text{C} \text{ (V}_{in} = 4.0 \text{ V to } 7.0 \text{ V, I}_{out} = 10 \text{ mA to } 3.0 \text{ A)}$		2.450 (-2%)	2.500	2.550 (+2%)	
5.0 V Regulator		, ,			
$T_A = 25$ °C ($V_{in} = 6.5$ V to 7.0 V, $I_{out} = 10$ mA to 3.0 A)		4.950 (-1%)	5.000	5.050 (+1%)	
$T_A = -20 \text{ to } +125^{\circ}\text{C} \text{ (V}_{in} = 6.5 \text{ V to } 7.0 \text{ V, I}_{out} = 10 \text{ mA to } 3.0 \text{ A)}$		4.925 (-1.5%)	5.000	5.075 (+1.5%)	
$T_A = -40 \text{ to } +150^{\circ}\text{C} \text{ (V}_{in} = 6.5 \text{ V to } 7.0 \text{ V, I}_{out} = 10 \text{ mA to } 3.0 \text{ A)}$		4.900 (-2%)	5.000	5.100 (+2%)	
Line Regulation (I _{out} = 10 mA, V _{out} +1.5 V < V _{in} < 7.0 V) (Note 5)	REG _{line}	-	0.03	-	%
Load Regulation (10 mA < I _{out} < 3.0 A) (Note 5)	REG _{load}	-	0.2	-	%
Dropout Voltage (I _{out} = 3.0 A)	V_{DO}	-	1.0	1.3	V
Peak Output Current Limit	l _{out}	3.0	-	-	Α
Internal Current Limitation (Note 5)	I _{lim}	-	4.5	-	Α
Ripple Rejection (120 Hz) (Note 5)	RR	-	70	-	dB
Ripple Rejection (1 kHz) (Note 5)		-	65	-	
Output Noise Voltage (V_{out} = 2.5 V, I_{out} = 10 mA, C_{out} = 1.0 μ F, f = 10 Hz to 100 kHz) (Note 5)	V _n	-	57	-	μV_{rms}
Thermal Shutdown (Note 5)	T _{SHD}	-	160	-	°C
Ground Current (I _{out} = 3.0 A) 2.5 V Regulator 5.0 V Regulator	I _{GND}	-	1.8 2.4	3.0 3.0	mA
Disable Current	l		2.7	0.0	^
2.5 V Regulator 5.0 V Regulator	I _{DIS}	- -	50 10	300 300	μΑ
Enable Input Threshold Voltage	V _{en}				V
Voltage Increasing, On state, Logic High Voltage Decreasing, Off state, Logic Low		1.3 -	-	0.3	
Enable Input Current (Note 5)	I _{en}				
Enable Pin Voltage = 0.3 V _{max} Enable Pin Voltage = 1.3 V _{min}		- -	0.5 0.5	-	μΑ

^{4.} Performance guaranteed over specified operating conditions by design, guard banded test limits, and/or characterization, production tested at T_J = T_A = 25°C. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible.

5. Typical values are based on design and/or characterization.

^{6.} Other fixed output voltages available at 0.9 V, 1.2 V, 1.5 V, 1.8 V, 3.0 V, 3.3 V per request.

TYPICAL CHARACTERISTICS

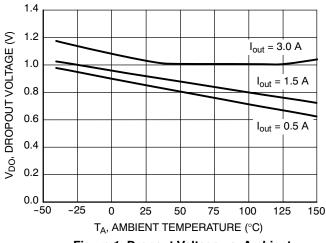


Figure 1. Dropout Voltage vs. Ambient Temperature

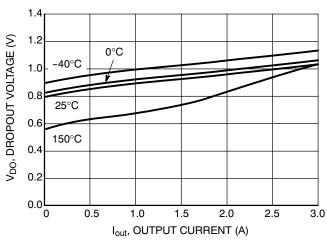


Figure 2. Dropout Voltage vs. Output Current

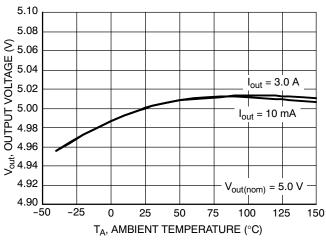


Figure 3. Output Voltage vs. Ambient Temperature

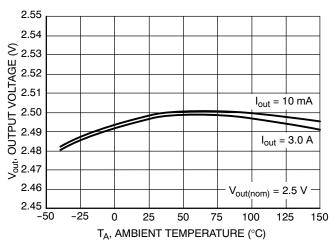


Figure 4. Output Voltage vs. Ambient Temperature

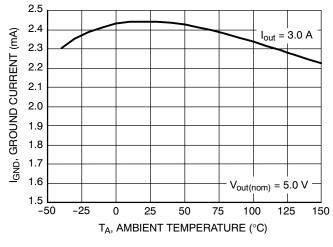


Figure 5. Ground Current vs. Ambient Temperature

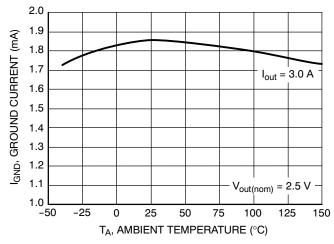
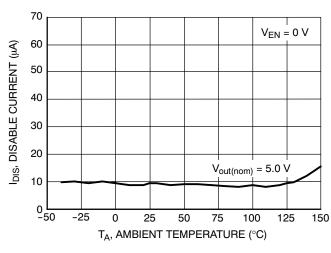


Figure 6. Ground Current vs. Ambient Temperature

TYPICAL CHARACTERISTICS

1.2

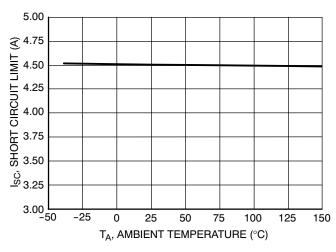


70 $V_{EN} = 0 V$ 60 DIS, DISABLE CURRENT (µA) 50 40 30 20 10 $V_{out(nom)} = 2.5 V$ 0 <u>L</u> -50 -25 0 25 50 75 100 150 TA, AMBIENT TEMPERATURE (°C)

Figure 7. Disable Current vs. Ambient Temperature

Figure 8. Disable Current vs. Ambient Temperature

T_A = 25°C



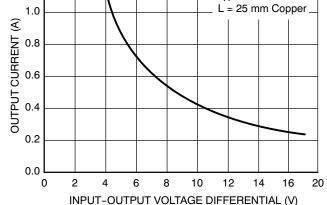
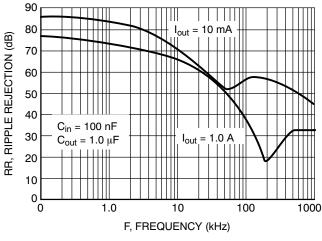


Figure 9. Short Circuit Current Limit vs. Ambient Temperature

Figure 10. Output Current vs. Input-Output Voltage Differential



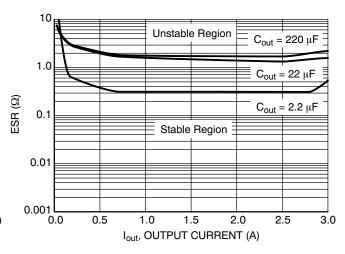
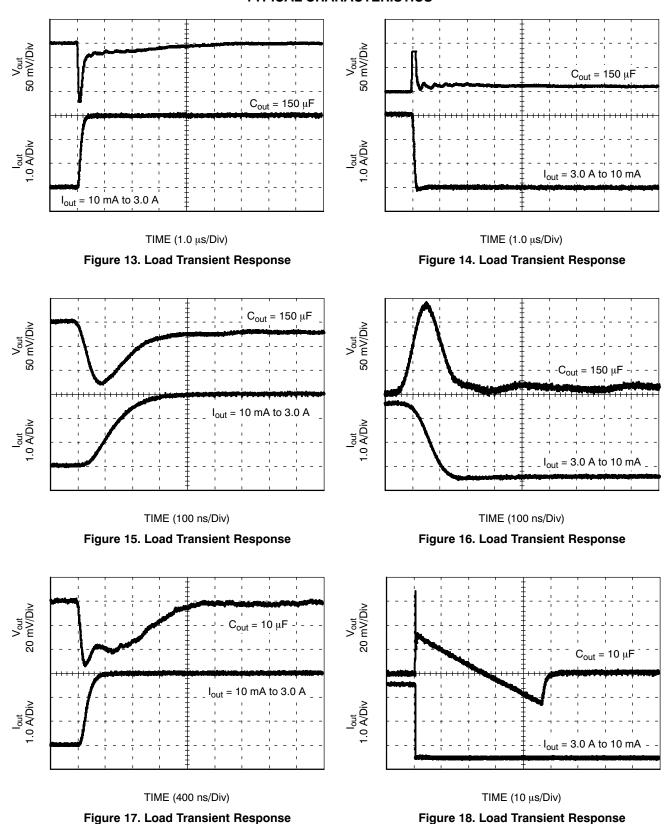


Figure 11. Ripple Rejection vs. Frequency

Figure 12. Output Capacitor ESR Stability vs.
Output Current

TYPICAL CHARACTERISTICS



NOTE: Typical characteristics were measured with the same conditions as electrical characteristics, unless otherwise noted.

APPLICATION INFORMATION

The NCP5666 is a high performance low dropout 3.0 A linear regulator with Enable suitable for high power applications. It is thermally robust and includes the safety features necessary during a fault condition, which provide for an attractive high current LDO solution for server, ASIC power supplies, networking equipment applications, and many others.

Input Capacitor

An input bypass capacitor is recommended to improve transient response or if the regulator is located more than a few inches from the power source. This will reduce the circuit's sensitivity to the input line impedance at high frequencies and significantly enhance the output transient response. Different types and different sizes of input capacitors can be chosen dependent on the quality of power supply. The range of 4.7 μF to 220 μF should cover most of the applications. The higher the capacitance, the lower change of input voltage due to line and load transients. The bypass capacitor should be mounted with shortest possible lead or track length directly across the regulator's input terminals.

Output Capacitor

The output capacitor is required for stability. The NCP5666 remains stable with ceramic, tantalum, and aluminum electrolytic capacitors with a minimum value of 2.2 μF . See Figure 12 for stable region of ESR for various output capacitors. The range of 2.2 μF to 220 μF should cover most of the applications. The higher the capacitance, the better load transient response. When a high value capacitor is used, a low value capacitor is also recommended to be put in parallel. The output capacitors should be placed as close as possible to the output pin of the device. This should help ensure ultrafast transient response times.

Current Limit Operation

As the peak output current increases beyond its limitation, the device is internally clampled to 4.5 A, thus causing the output voltage to decrease and go out of regulation. This allows the device never to exceed the maximum power dissipation.

Input Voltage Operating Range

The NCP5666 is guaranteed to protect itself from self destruction due to excessive power dissipation by activating current limit and thermal shutdown protections. These destructive situations can happen during very fast startup with large output capacitors or when output is short circuited. As long as the input voltage is lower than maximum operating voltage (9 V), the maximum power dissipation is never exceeded.

If input voltage is between maximum operating voltage (9 V) and absolute maximum voltage (18 V) power dissipation must never exceed limits specified in Thermal Consideration section for safety operation.

To use the device over maximum operating voltage the slow startup, not large output capacitors and no short circuit is recommended to maintain.

Thermal Consideration

The maximum device power dissipation can be calculated by:

$$P_{D} = \frac{T_{J(max)} - T_{A}}{R_{\theta JA}}$$

The bipolar process employed for this IC is fully characterized and rated for reliable 18 V operation. To avoid damaging the part or degrading it's reliability, power dissipation transients should be limited to 30 W for D²PAK. For open-circuit to short-circuit transient,

PDTransient = Vin(operating max) * ISC

ORDERING INFORMATION

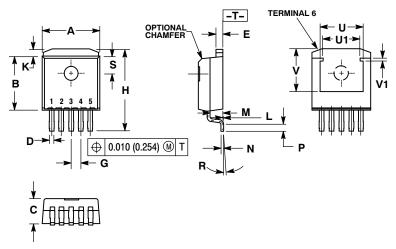
Device	Nominal Output Voltage	Package	Shipping†
NCP5666DS25R4G (Note 7)	2.5 V	D ² PAK (Pb-Free)	800 / Tape & Reel
NCP5666DS50R4G (Note 7)	5.0 V	D ² PAK (Pb-Free)	800 / Tape & Reel

^{7.} Other fixed output voltages available at 0.9 V, 1.2 V, 1.5 V, 1.8 V, 3.0 V, 3.3 V per request.

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS

D²PAK 5 CASE 936A-02 ISSUE D

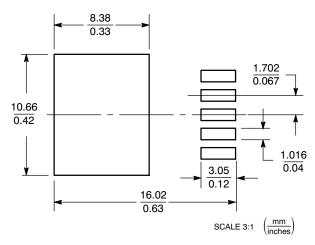


NOTES

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: INCH.
 TAB CONTOUR OPTIONAL WITHIN DIMENSIONS A AND K.
- DIMENSIONS U AND V ESTABLISH A MINIMUM MOUNTING SURFACE FOR TERMINAL 6.
- DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH OR GATE PROTRUSIONS. MOLD FLASH AND GATE PROTRUSIONS NOT TO EXCEED 0.025 (0.635) MAXIMUM.

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.386	0.403	9.804	10.236	
В	0.356	0.368	9.042	9.347	
С	0.170	0.180	4.318	4.572	
D	0.026	0.036	0.660	0.914	
E	0.045	0.055	1.143	1.397	
G	0.067	BSC	1.702 BSC		
Н	0.539	0.579	13.691	14.707	
K	0.050	REF	1.270 REF		
L	0.000	0.010	0.000	0.254	
M	0.088	0.102	2.235	2.591	
N	0.018	0.026	0.457	0.660	
Р	0.058	0.078	1.473	1.981	
R	5° I	REF	5° F	REF	
S	0.116 REF		2.946	REF	
U	0.200 MIN		5.080	MIN (
V	0.250 MIN		6.350	MIN	
U1	0.297	0.305	7.544	7.747	
V1	0.038	0.046	0.965	1.168	

SOLDERING FOOTPRINT*



^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

The products described herein (NCP5666), may be covered by one or more of the following U.S. patents: 5,920,184; 5,834,926. There may be other patents pending.

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